



Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 1.3A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

450V NPN HIGH VOLTAGE POWER TRANSISTOR

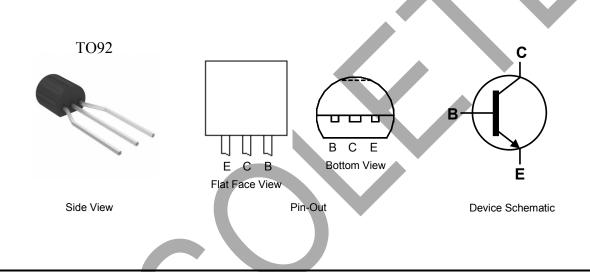
Mechanical Data

- Case: TO92 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish;
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: TO92: 200mg (Approximate)

Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
 - Power Supply for DVD / STB
- LED Lighting



Ordering Information (Note 4)

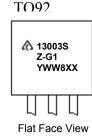
Product	Package	Marking	Quantity
APT13003SZTR-G1	TO92 (Joggled Legs)	13003SZ-G1	2000 Taped, per Ammo Box

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Manufacturers' Code Marking
 13003SZ-G1 = Product Type Marking ID
 YWW = Date Code Marking
 e.g. 012 = Year 2020, Week 12.
 8 = Assembly Site Code
 XX = Batch Number



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	I _C	1.3	А
Peak Pulse Collector Current (Note 5)	I _{CM}	2.6	А
Continuous Base Current	IB	0.65	А
Peak Pulse Base Current (Note 5)	I _{BM}	1.3	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

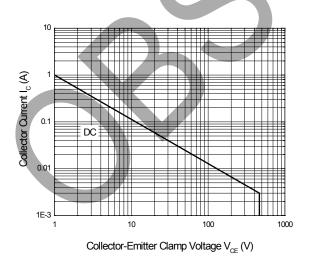
Characteristic	Symbol	Value	Unit
Power Dissipation	PD	1.1	W
Thermal Resistance, Junction to Ambient Air	R _{0JA}	113.6	°C/W
Thermal Resistance, Junction to Case	R _{ejc}	83.3	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C

ESD Ratings (Note 6)

Characteristic		Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model		ESD HBM	8000	V	3B
Electrostatic Discharge - Machine Model		ESD MM	400	V	С

Note: 5. Pulse test for Pulse Width < 5ms, Duty Cycle ≤ 10%. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Area and Derating Information (@T_A = +25°C, unless otherwise specified.)



Safe Operating Areas (TO92 Package)

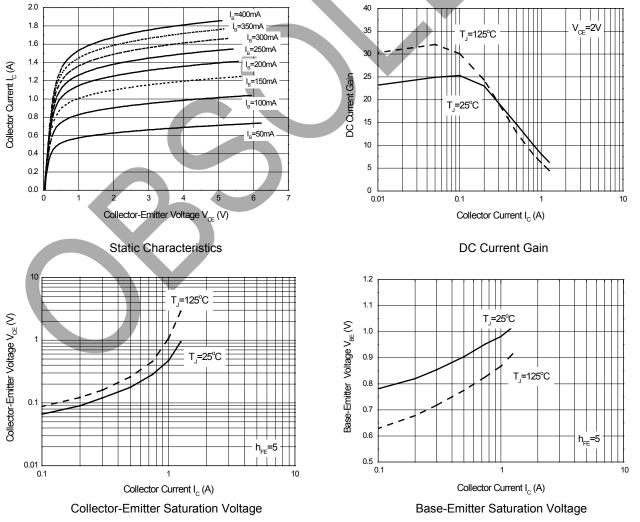


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	—	_	V	I _C = 100μA, V _{BE} = 0V
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	—	—	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	_	—	10	μA	V _{CE} = 700V, V _{BE} = -1.5V
DC Current Transfer Static Ratio (Note 7)	h _{FE}	13 5	_	30 25	_	I _C = 0.5A, V _{CE} = 2V I _C = 1.0A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}		_	0.3 0.6	V	$I_{C} = 0.5A, I_{B} = 0.1A$ $I_{C} = 1A, I_{B} = 0.25A$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}		_	1.0 1.2	V	$I_{C} = 0.5A, I_{B} = 0.1A$ $I_{C} = 1A, I_{B} = 0.25A$
Transition Frequency	f⊤	4	_	—	MHz	I _C = 0.1A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	_	_	1		
Storage Time with Resistive Load	ts	_	—	3	μs	$I_{\rm C} = 1$ A, $V_{\rm CC} = 125$ V, $I_{\rm B1} = 0.2$ A
Fall Time with Resistive Load	t _f	_	—	0.5		I _{B2} = -0.2A, t _p = 25µs

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

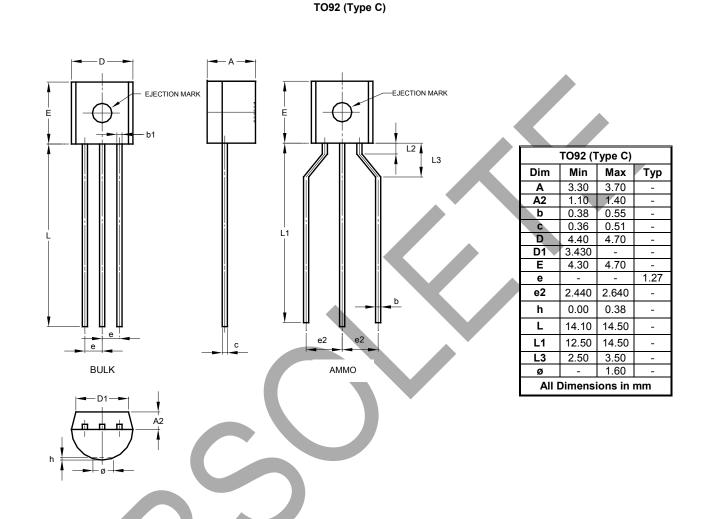
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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